

## 具有开漏比较器和基准的 INA20x 高侧测量电流分流监控器

### 1 特性

- 完整电流感测解决方案
- 三种增益可供选择：
  - INA200 = 20V/V
  - INA201 = 50V/V
  - INA202 = 100V/V
- 0.6V 内部电压基准
- 内部漏极开路比较器
- 比较器锁存功能
- 共模范围：-16V 至 80V
- 高精度：整个温度范围内的最大误差为 3.5%
- 带宽：500kHz (INA200)
- 静态电流：1800μA（最大值）
- 封装：SOIC-8、VSSOP-8

### 2 应用

- 笔记本电脑
- 手机
- 电信设备
- 汽车
- 电源管理
- 电池充电器
- 焊接设备

### 3 说明

INA200、INA201 和 INA202 器件是具有电压输出和集成比较器的高侧电流分流监控器。INA20x 器件能够在 -16V 至 +80V 范围内的共模电压下感测分流器两端的压降。INA20x 系列器件可提供三种输出电压级别，即 20V/V、50V/V 和 100V/V，带宽高达 500kHz。

INA200、INA201 和 INA202 器件整合了一个开漏比较器以及提供 0.6V 阈值的内部基准。外部分压器可设定电流跳变点。比较器具有锁存功能，可通过将 **RESET** 引脚接地（或悬空）进入透明状态。

INA200、INA201 和 INA202 器件由单个 2.7V 至 18V 电源供电，消耗的最大电源电流为 1800μA。封装选项包括极小型 VSSOP-8 和

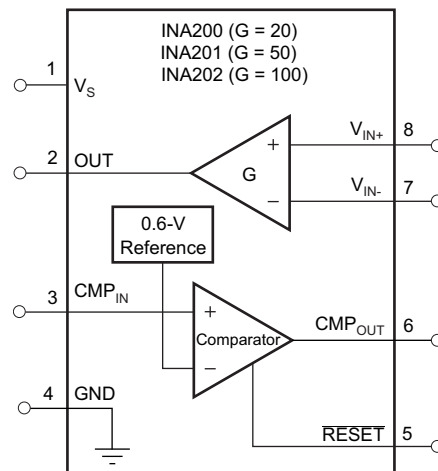
SOIC-8。所有版本的额定扩展工作温度范围均为 -40°C 至 +125°C。

器件信息<sup>(1)</sup>

| 器件型号                       | 封装        | 封装尺寸（标称值）       |
|----------------------------|-----------|-----------------|
| INA200<br>INA201<br>INA202 | SOIC (8)  | 4.90mm x 3.91mm |
|                            | VSSOP (8) | 3.00mm x 3.00mm |

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

简化电路原理图



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## 4 修订历史记录

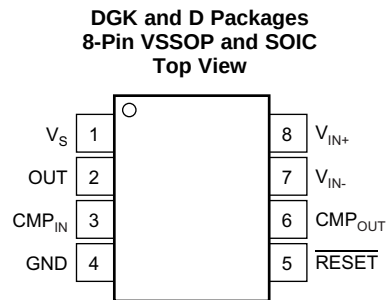
注：之前版本的页码可能与当前版本有所不同。

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| • Corrected typo in <i>Voltage Output</i> section in <i>Electrical Characteristics</i> table .....       | <b>6</b>  |
| • 已添加 text to <i>Comparator</i> subsection in <i>Feature Description</i> section .....                   | <b>14</b> |
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| • 已添加 图 36, 图 37, and 图 38 .....                                                                         | <b>23</b> |

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|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|
| • Added <i>ESD Ratings</i> table, <i>Thermal Information</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section ..... | <b>4</b> |

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| • 修改了首页上的原理图 .....                                    | <b>1</b> |
| • 已更改 数据表标题 .....                                     | <b>1</b> |
| • 根据最新标准更新了文档格式 .....                                 | <b>1</b> |

## 5 Pin Configuration and Functions



**Pin Functions**

| PIN                       |     | I/O           | DESCRIPTION                      |
|---------------------------|-----|---------------|----------------------------------|
| NAME                      | NO. |               |                                  |
| CMP <sub>IN</sub>         | 3   | Analog input  | Comparator input                 |
| CMP <sub>OUT</sub>        | 6   | Analog output | Comparator output                |
| GND                       | 4   | Analog        | Ground                           |
| OUT                       | 2   | Analog output | Output voltage                   |
| $\overline{\text{RESET}}$ | 5   | Analog input  | Comparator reset pin, active low |
| V <sub>IN-</sub>          | 7   | Analog input  | Connect to shunt low side        |
| V <sub>IN+</sub>          | 8   | Analog input  | Connect to shunt high side       |
| V <sub>S</sub>            | 1   | Analog        | Power supply                     |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

 over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                                                            |                                            | MIN       | MAX             | UNIT |
|------------------------------------------------------------|--------------------------------------------|-----------|-----------------|------|
| Supply voltage, $V_S$                                      |                                            | 2.7       | 18              | V    |
| Current-shunt monitor analog inputs, $V_{IN+}$ , $V_{IN-}$ | Differential ( $V_{IN+}$ ) – ( $V_{IN-}$ ) | –18       | 18              | V    |
|                                                            | Common-mode <sup>(2)</sup>                 | –16       | 80              | V    |
| Comparator analog input and reset pins <sup>(2)</sup>      |                                            | GND – 0.3 | ( $V_S$ ) + 0.3 | V    |
| Analog output, OUT <sup>(2)</sup>                          |                                            | GND – 0.3 | ( $V_S$ ) + 0.3 | V    |
| Comparator output, OUT <sup>(2)</sup>                      |                                            | GND – 0.3 | 18              | V    |
| Input current into any pin <sup>(2)</sup>                  |                                            |           | 5               | mA   |
| Operating temperature                                      |                                            | –55       | 150             | °C   |
| Junction temperature                                       |                                            | –65       | 150             | °C   |
| Storage temperature, $T_{stg}$                             |                                            | –65       | 150             | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) This voltage may exceed the ratings shown if the current at that pin is limited to 5 mA.

### 6.2 ESD Ratings

|                                     |                                                                                          | VALUE | UNIT |
|-------------------------------------|------------------------------------------------------------------------------------------|-------|------|
| $V_{(ESD)}$ Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>              | ±4000 | V    |
|                                     | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup> | ±1000 |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|          |                                | MIN | NOM | MAX | UNIT |
|----------|--------------------------------|-----|-----|-----|------|
| $V_{CM}$ | Common-mode input voltage      | –16 | 12  | 80  | V    |
| $V_S$    | Operating supply voltage       | 2.7 | 12  | 18  | V    |
| $T_A$    | Operating free-air temperature | –40 | 25  | 125 | °C   |

### 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | INA20x   |            | UNIT |
|-------------------------------|----------------------------------------------|----------|------------|------|
|                               |                                              | D (SOIC) | DGK (SOIC) |      |
|                               |                                              | 8 PINS   | 8 PINS     |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 110.5    | 162.2      | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 50.4     | 37.7       | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 52.7     | 82.9       | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 7.8      | 1.3        | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 51.9     | 81.4       | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics: Current-Shunt Monitor

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{CM} = 12\text{ V}$ ,  $V_{SENSE} = 100\text{ mV}$ ,  $R_L = 10\text{ k}\Omega$  to GND,  $R_{PULL-UP} = 5.1\text{ k}\Omega$  connected from  $CMP_{OUT}$  to  $V_S$ , and  $CMP_{IN} = \text{GND}$ , (unless otherwise noted)

| PARAMETER    |                                      | TEST CONDITIONS                                                                                                      | MIN | TYP       | MAX                          | UNIT                         |
|--------------|--------------------------------------|----------------------------------------------------------------------------------------------------------------------|-----|-----------|------------------------------|------------------------------|
| <b>INPUT</b> |                                      |                                                                                                                      |     |           |                              |                              |
| $V_{SENSE}$  | Full-scale sense input voltage       | $V_{SENSE} = V_{IN+} - V_{IN-}$                                                                                      |     | 0.15      | $(V_S - 0.25) / \text{Gain}$ | V                            |
| $V_{CM}$     | Common-mode input range              | $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$                                                                     | -16 |           | 80                           | V                            |
| CMR          | Common-mode rejection                | $V_{IN+} = -16\text{ V}$ to $80\text{ V}$                                                                            | 80  | 100       |                              | dB                           |
|              |                                      | $V_{IN+} = 12\text{ V}$ to $80\text{ V}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$                          | 100 | 123       |                              | dB                           |
| $V_{OS}$     | Offset voltage, RTI <sup>(1)</sup>   | $T_A = 25^\circ\text{C}$                                                                                             |     | $\pm 0.5$ | $\pm 2.5$                    | mV                           |
|              |                                      | $T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$                                                                      |     |           | $\pm 3$                      | mV                           |
|              |                                      | $T_A = -40^\circ\text{C}$ to $25^\circ\text{C}$                                                                      |     |           | $\pm 3.5$                    | mV                           |
| $dV_{OS}/dT$ | Offset voltage, RTI, vs temperature  | $T_{MIN}$ to $T_{MAX}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$                                            |     | 5         |                              | $\mu\text{V}/^\circ\text{C}$ |
| PSR          | Offset voltage, RTI, vs power supply | $V_{OUT} = 2\text{ V}$ , $V_{IN+} = 18\text{ V}$ , $2.7\text{ V}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$ |     | 2.5       | 100                          | $\mu\text{V}/\text{V}$       |
| $I_B$        | Input bias current, $V_{IN-}$ pin    | $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$                                                                     |     | $\pm 9$   | $\pm 16$                     | $\mu\text{A}$                |

(1) Offset is extrapolated from measurements of the output at 20-mV and 100-mV  $V_{SENSE}$ .

**INA200, INA201, INA202**

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[www.ti.com.cn](http://www.ti.com.cn)
**Electrical Characteristics: Current-Shunt Monitor (continued)**

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{CM} = 12\text{ V}$ ,  $V_{SENSE} = 100\text{ mV}$ ,  $R_L = 10\text{ k}\Omega$  to GND,  $R_{PULL-UP} = 5.1\text{ k}\Omega$  connected from  $CMP_{OUT}$  to  $V_S$ , and  $CMP_{IN} = \text{GND}$ , (unless otherwise noted)

| PARAMETER                                                              |                                    | TEST CONDITIONS                                                                                     | MIN                      | TYP                    | MAX                   | UNIT                   |
|------------------------------------------------------------------------|------------------------------------|-----------------------------------------------------------------------------------------------------|--------------------------|------------------------|-----------------------|------------------------|
| <b>OUTPUT (<math>V_{SENSE} \geq 20\text{ mV}</math>)</b>               |                                    |                                                                                                     |                          |                        |                       |                        |
| G                                                                      | Gain                               | INA200                                                                                              |                          | 20                     |                       | V/V                    |
|                                                                        |                                    | INA201                                                                                              |                          | 50                     |                       | V/V                    |
|                                                                        |                                    | INA202                                                                                              |                          | 100                    |                       | V/V                    |
|                                                                        | Gain error                         | $V_{SENSE} = 20\text{ mV to }100\text{ mV}$                                                         |                          | $\pm 0.2\%$            | $\pm 1\%$             |                        |
|                                                                        |                                    | $V_{SENSE} = 20\text{ mV to }100\text{ mV}$ , $T_A = -40^\circ\text{C to }125^\circ\text{C}$        |                          |                        | $\pm 2\%$             |                        |
|                                                                        | Total output error <sup>(2)</sup>  | $V_{SENSE} = 120\text{ mV}$ , $V_S = 16\text{ V}$                                                   |                          | $\pm 0.75\%$           | $\pm 2.2\%$           |                        |
|                                                                        |                                    | $V_{SENSE} = 120\text{ mV}$ , $V_S = 16\text{ V}$ , $T_A = -40^\circ\text{C to }125^\circ\text{C}$  |                          |                        | $\pm 3.5\%$           |                        |
|                                                                        | Nonlinearity error <sup>(3)</sup>  | $V_{SENSE} = 20\text{ mV to }100\text{ mV}$                                                         |                          | $\pm 0.002\%$          |                       |                        |
| $R_O$                                                                  | Output impedance                   |                                                                                                     |                          | 1.5                    |                       | $\Omega$               |
|                                                                        | Maximum capacitive load            | No sustained oscillation                                                                            |                          | 10                     |                       | nF                     |
| <b>OUTPUT (<math>V_{SENSE} &lt; 20\text{ mV}</math>)<sup>(4)</sup></b> |                                    |                                                                                                     |                          |                        |                       |                        |
| Output                                                                 | INA200, INA201, INA202             | $-16\text{ V} \leq V_{CM} < 0\text{ V}$                                                             |                          | 300                    |                       | mV                     |
|                                                                        | INA200                             | $0\text{ V} \leq V_{CM} \leq V_S$ , $V_S = 5\text{ V}$                                              |                          |                        | 0.4                   | V                      |
|                                                                        | INA201                             | $0\text{ V} \leq V_{CM} \leq V_S$ , $V_S = 5\text{ V}$                                              |                          |                        | 1                     | V                      |
|                                                                        | INA202                             | $0\text{ V} \leq V_{CM} \leq V_S$ , $V_S = 5\text{ V}$                                              |                          |                        | 2                     | V                      |
|                                                                        | INA200, INA201, INA202             | $V_S < V_{CM} \leq 80\text{ V}$                                                                     |                          | 300                    |                       | mV                     |
| <b>VOLTAGE OUTPUT<sup>(5)</sup></b>                                    |                                    |                                                                                                     |                          |                        |                       |                        |
|                                                                        | Output swing to the positive rail  | $V_{IN-} = 11\text{ V}$ , $V_{IN+} = 12\text{ V}$ , $T_A = -40^\circ\text{C to }125^\circ\text{C}$  |                          | $(V_S) - 0.15$         | $(V_S) - 0.25$        | V                      |
|                                                                        | Output swing to GND <sup>(6)</sup> | $V_{IN-} = 0\text{ V}$ , $V_{IN+} = -0.5\text{ V}$ , $T_A = -40^\circ\text{C to }125^\circ\text{C}$ |                          | $(\text{GND}) + 0.004$ | $(\text{GND}) + 0.05$ | V                      |
| <b>FREQUENCY RESPONSE</b>                                              |                                    |                                                                                                     |                          |                        |                       |                        |
| BW                                                                     | Bandwidth                          | INA200                                                                                              | $C_{LOAD} = 5\text{ pF}$ | 500                    |                       | kHz                    |
|                                                                        |                                    | INA201                                                                                              | $C_{LOAD} = 5\text{ pF}$ | 300                    |                       | kHz                    |
|                                                                        |                                    | INA202                                                                                              | $C_{LOAD} = 5\text{ pF}$ | 200                    |                       | kHz                    |
|                                                                        | Phase margin                       | $C_{LOAD} < 10\text{ nF}$                                                                           |                          | 40                     |                       | $^\circ\text{C}$       |
| SR                                                                     | Slew rate                          |                                                                                                     |                          | 1                      |                       | V/ $\mu\text{s}$       |
|                                                                        | Settling time (1%)                 | $V_{SENSE} = 10\text{ mV}_{PP}$ to $100\text{ mV}_{PP}$ ,<br>$C_{LOAD} = 5\text{ pF}$               |                          | 2                      |                       | $\mu\text{s}$          |
| <b>NOISE, RTI</b>                                                      |                                    |                                                                                                     |                          |                        |                       |                        |
|                                                                        | Voltage noise density              |                                                                                                     |                          | 40                     |                       | nV/ $\sqrt{\text{Hz}}$ |

(2) Total output error includes effects of gain error and  $V_{OS}$ .

(3) Linearity is best fit to a straight line.

(4) For details on this region of operation, see [Accuracy Variations](#) section in [Device Functional Modes](#).

(5) See [Figure 8](#).

(6) Specified by design.

## 6.6 Electrical Characteristics: Comparator

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{CM} = 12\text{ V}$ ,  $V_{SENSE} = 100\text{ mV}$ ,  $R_L = 10\text{ k}\Omega$  to GND, and  $R_{PULL-UP} = 5.1\text{ k}\Omega$  connected from  $CMP_{OUT}$  to  $V_S$ , (unless otherwise noted)

| PARAMETER                                                 | TEST CONDITIONS                                                                      | MIN                                                       | TYP    | MAX | UNIT |
|-----------------------------------------------------------|--------------------------------------------------------------------------------------|-----------------------------------------------------------|--------|-----|------|
| OFFSET VOLTAGE                                            |                                                                                      |                                                           |        |     |      |
| Threshold                                                 | T <sub>A</sub> = 25°C                                                                | 590                                                       | 608    | 620 | mV   |
|                                                           | T <sub>A</sub> = −40°C to 125°C                                                      | 586                                                       |        | 625 | mV   |
| Hysteresis <sup>(1)</sup>                                 | T <sub>A</sub> = −40°C to 85°C                                                       |                                                           | −8     |     | mV   |
| INPUT BIAS CURRENT <sup>(2)</sup>                         |                                                                                      |                                                           |        |     |      |
| Input bias current, CMP <sub>in</sub> PIN                 |                                                                                      |                                                           | 0.005  | 10  | nA   |
| Input bias current, CMP <sub>in</sub> PIN, vs temperature | T <sub>A</sub> = −40°C to 125°C                                                      |                                                           |        | 15  | nA   |
| INPUT VOLTAGE RANGE                                       |                                                                                      |                                                           |        |     |      |
| Input voltage range, CMP <sub>in</sub> PIN                |                                                                                      | 0 V to V <sub>S</sub> − 1.5 V                             |        |     | V    |
| OUTPUT (OPEN-DRAIN)                                       |                                                                                      |                                                           |        |     |      |
| Large-signal differential voltage gain                    | CMP V <sub>OUT</sub> 1 V to 4 V,<br>R <sub>L</sub> ≥ 15 kΩ connected to 5 V          |                                                           | 200    |     | V/mV |
| I <sub>LKG</sub>                                          | High-level leakage current <sup>(3)(4)</sup>                                         | V <sub>ID</sub> = 0.4 V, V <sub>OH</sub> = V <sub>S</sub> | 0.0001 | 1   | μA   |
| V <sub>OL</sub>                                           | Low-level output voltage <sup>(3)</sup>                                              | V <sub>ID</sub> = −0.6 V, I <sub>OL</sub> = 2.35 mA       | 220    | 300 | mV   |
| RESPONSE TIME                                             |                                                                                      |                                                           |        |     |      |
| Response time <sup>(5)</sup>                              | R <sub>L</sub> to 5 V, C <sub>L</sub> = 15 pF, 100-mV Input Step with 5-mV overdrive |                                                           | 1.3    |     | μs   |
| RESET                                                     |                                                                                      |                                                           |        |     |      |
| RESET threshold <sup>(6)</sup>                            |                                                                                      |                                                           | 1.1    |     | V    |
| Logic input impedance                                     |                                                                                      |                                                           | 2      |     | MΩ   |
| Minimum RESET pulse width                                 |                                                                                      |                                                           | 1.5    |     | μs   |
| RESET propagation delay                                   |                                                                                      |                                                           | 3      |     | μs   |

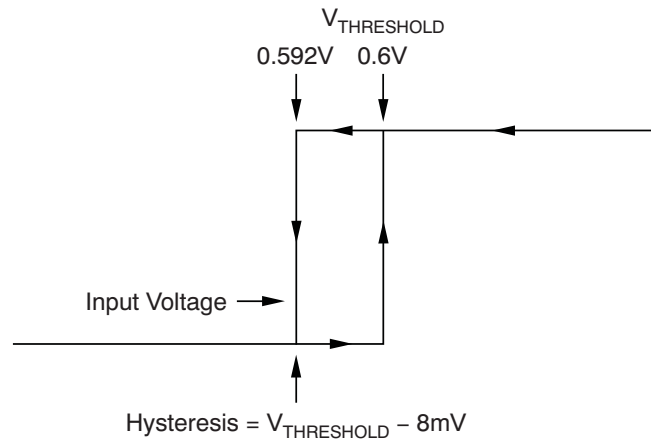
- (1) Hysteresis refers to the threshold (the threshold specification applies to a rising edge of a noninverting input) of a falling edge on the noninverting input of the comparator; refer to [Figure 1](#).
- (2) Specified by design.
- (3)  $V_{ID}$  refers to the differential voltage at the comparator inputs.
- (4) Open-drain output can be pulled to the range of 2.7 to 18 V, regardless of  $V_S$ .
- (5) The comparator response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.
- (6) The RESET input has an internal 2 M $\Omega$  (typical) pull-down. Leaving RESET open results in a LOW state, with transparent comparator operation.

## 6.7 Electrical Characteristics: General

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{CM} = 12\text{ V}$ ,  $V_{SENSE} = 100\text{ mV}$ ,  $R_L = 10\text{ k}\Omega$  to GND,  $R_{PULL-UP} = 5.1\text{ k}\Omega$  connected from  $CMP_{OUT}$  to  $V_S$ , and  $CMP_{IN} = 1\text{ V}$ , unless otherwise noted.

| PARAMETER                                          | TEST CONDITIONS                                                              | MIN | TYP  | MAX  | UNIT               |
|----------------------------------------------------|------------------------------------------------------------------------------|-----|------|------|--------------------|
| <b>POWER SUPPLY</b>                                |                                                                              |     |      |      |                    |
| $V_S$ Operating power supply                       | $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$                             | 2.7 |      | 18   | V                  |
| $I_Q$ Quiescent current                            | $V_{OUT} = 2\text{ V}$                                                       |     | 1350 | 1800 | $\mu\text{A}$      |
|                                                    | $V_{SENSE} = 0\text{ mV}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$ |     |      | 1850 | $\mu\text{A}$      |
| Comparator power-on reset threshold <sup>(1)</sup> |                                                                              |     | 1.5  |      | V                  |
| <b>TEMPERATURE</b>                                 |                                                                              |     |      |      |                    |
| Specified temperature                              |                                                                              | -40 |      | 125  | $^\circ\text{C}$   |
| Operating temperature                              |                                                                              | -55 |      | 150  | $^\circ\text{C}$   |
| Storage temperature                                |                                                                              | -65 |      | 150  | $^\circ\text{C}$   |
| $\theta_{JA}$ Thermal resistance                   | VSSOP-8 Surface-Mount                                                        |     | 200  |      | $^\circ\text{C/W}$ |
|                                                    | SOIC-8                                                                       |     | 150  |      | $^\circ\text{C/W}$ |

- (1) The INA200, INA201, and INA202 are designed to power-up with the comparator in a defined reset state as long as RESET is open or grounded. The comparator is in reset as long as the power supply is below the voltage shown here. The comparator assumes a state based on the comparator input above this supply voltage. If RESET is high at power-up, the comparator output comes up high and requires a reset to assume a low state, if appropriate.



**图 1. Typical Comparator Hysteresis**



## 6.8 Typical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{IN+} = 12\text{ V}$ , and  $V_{SENSE} = 100\text{ mV}$ , (unless otherwise noted)

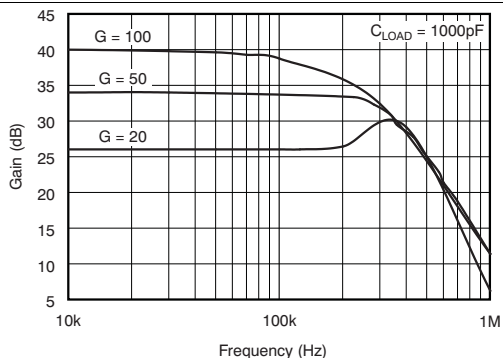


图 2. Gain vs Frequency

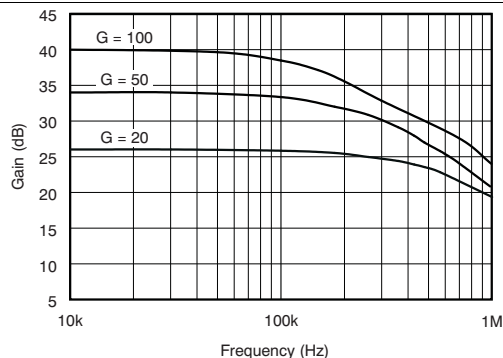


图 3. Gain vs Frequency

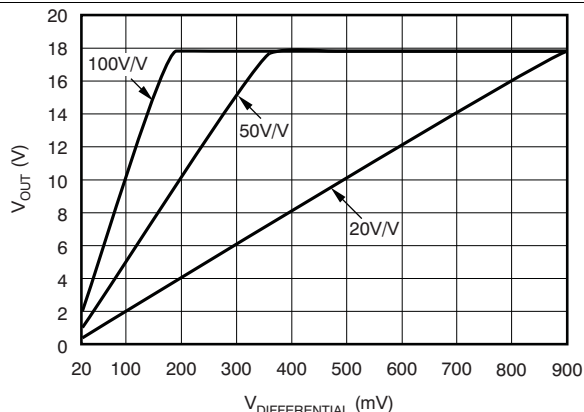


图 4. Gain Plot

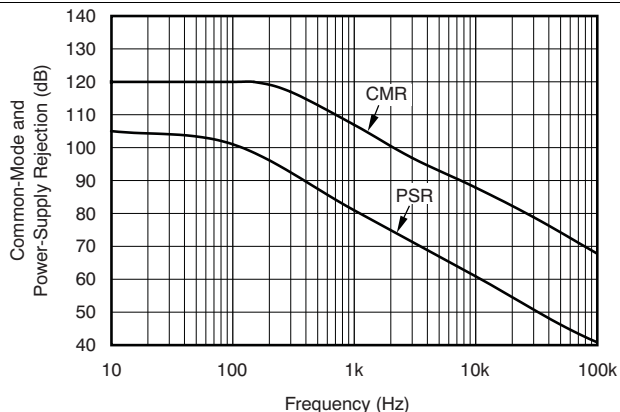


图 5. Common-Mode and Power-Supply Rejection vs Frequency

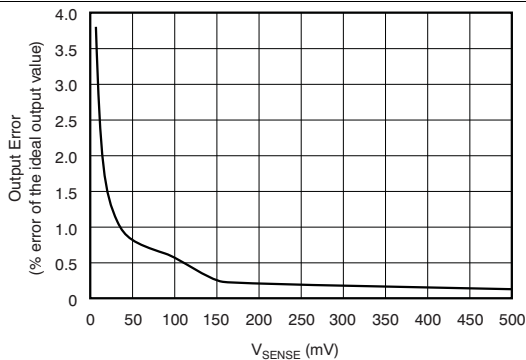


图 6. Output Error vs  $V_{SENSE}$

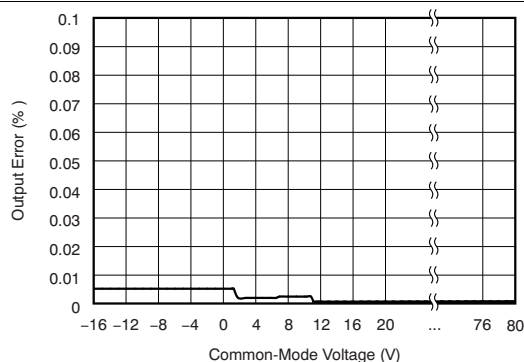


图 7. Output Error vs Common-Mode Voltage

## Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{IN+} = 12\text{ V}$ , and  $V_{SENSE} = 100\text{ mV}$ , (unless otherwise noted)

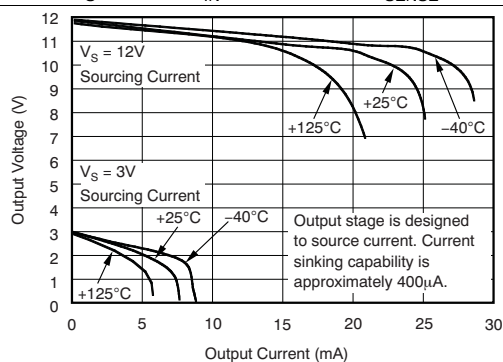


图 8. Positive Output Voltage Swing vs Output Current

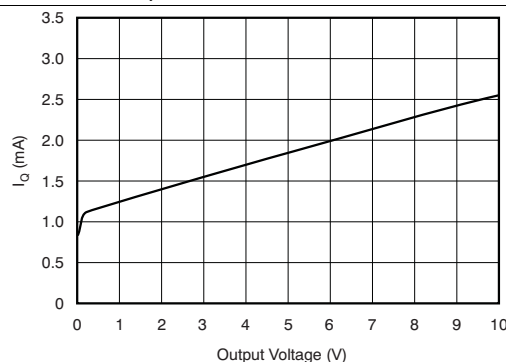


图 9. Quiescent Current vs Output Voltage

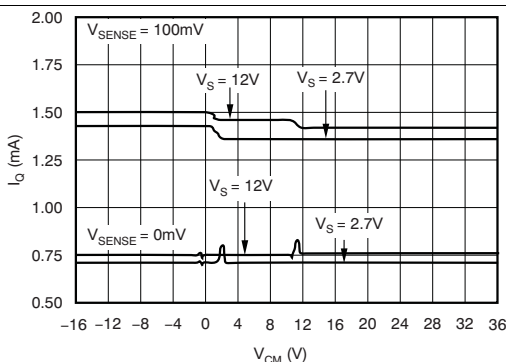


图 10. Quiescent Current vs Common-Mode Voltage

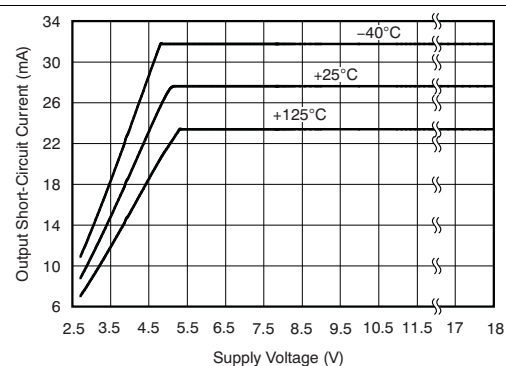


图 11. Output Short-Circuit Current vs Supply Voltage

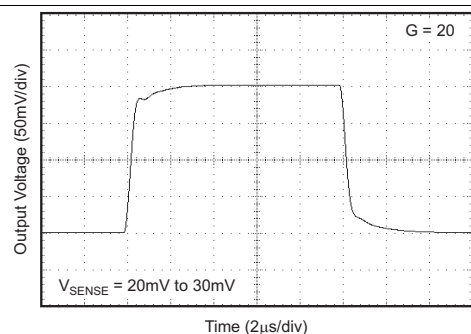


图 12. Step Response

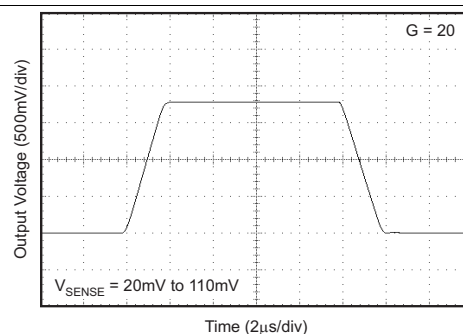


图 13. Step Response

## Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{IN+} = 12\text{ V}$ , and  $V_{SENSE} = 100\text{ mV}$ , (unless otherwise noted)

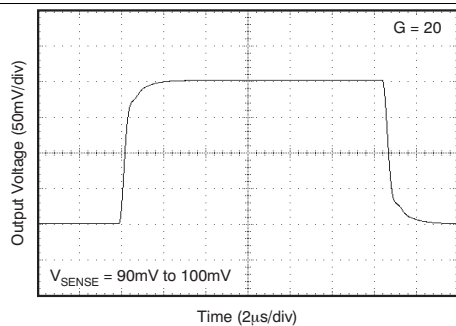


图 14. Step Response

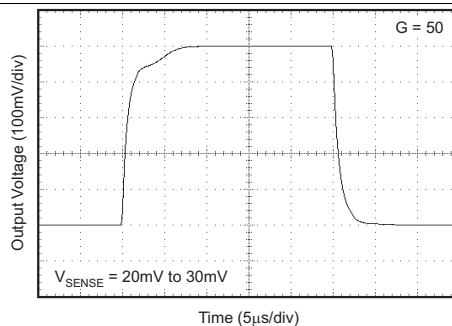


图 15. Step Response

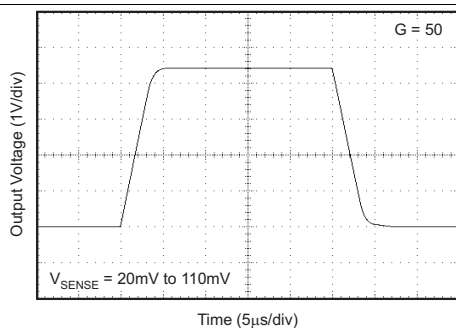


图 16. Step Response

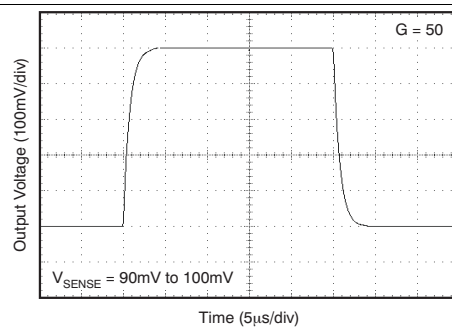


图 17. Step Response

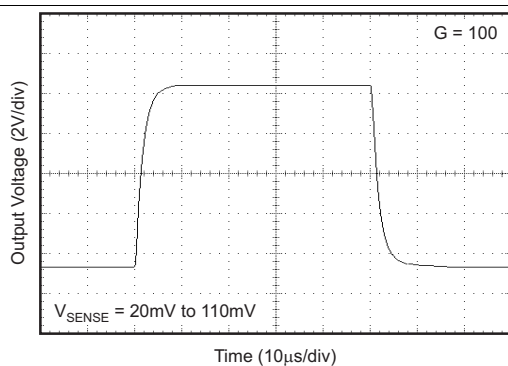


图 18. Step Response

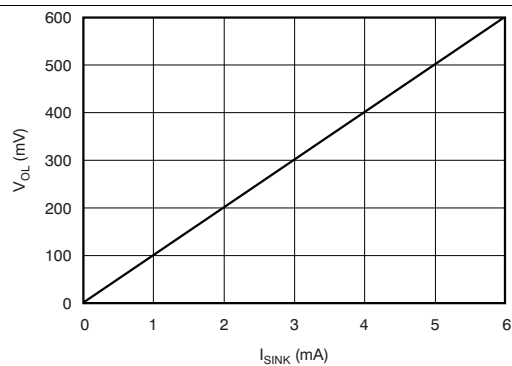


图 19. Comparator  $V_{OL}$  vs  $I_{SINK}$

## Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{IN+} = 12\text{ V}$ , and  $V_{SENSE} = 100\text{ mV}$ , (unless otherwise noted)

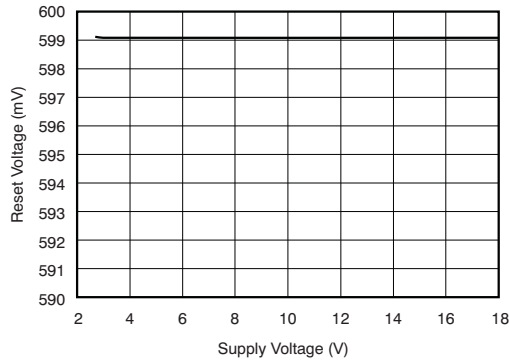


图 20. Comparator Trip Point vs Supply Voltage

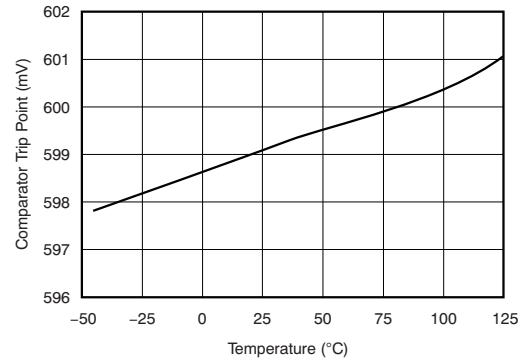


图 21. Comparator Trip Point vs Temperature

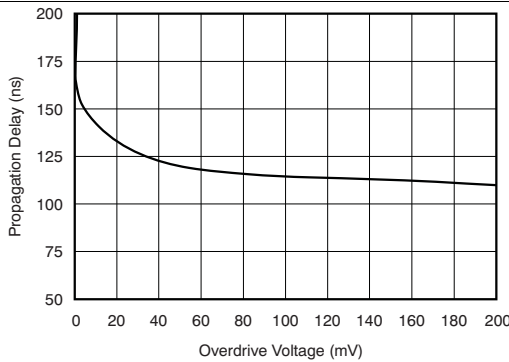


图 22. Comparator Propagation Delay vs Overdrive Voltage

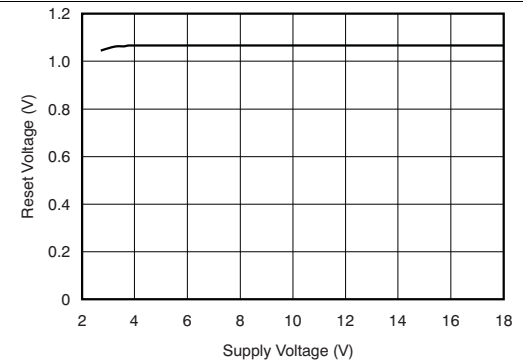


图 23. Comparator Reset Voltage vs Supply Voltage

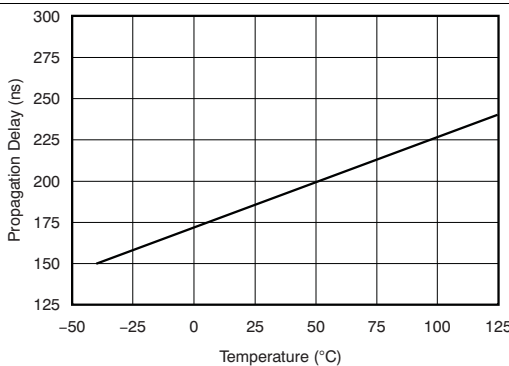


图 24. Comparator Propagation Delay vs Temperature

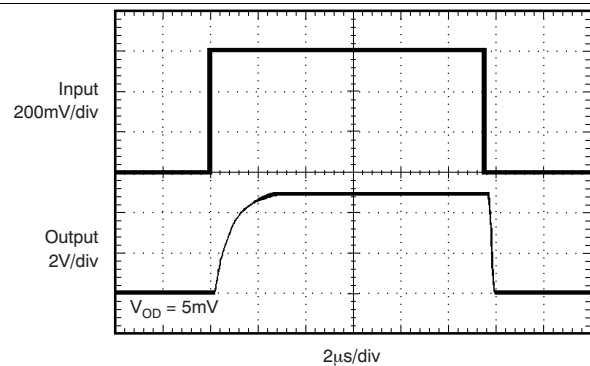


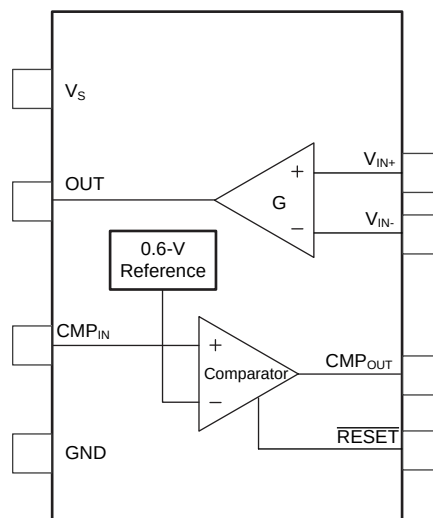
图 25. Comparator Propagation Delay

## 7 Detailed Description

### 7.1 Overview

The INA200, INA201, and INA202 devices are high-side current-shunt monitors with voltage output. The INA20x devices can sense drops across shunts at common-mode voltages from  $-16\text{ V}$  to  $80\text{ V}$ . The INA200–INA202 devices are available with three output voltage scales:  $20\text{ V/V}$ ,  $50\text{ V/V}$ , and  $100\text{ V/V}$ , with up to  $500\text{-kHz}$  bandwidth. The INA200, INA201, and INA202 devices incorporate an open-drain comparator and internal reference providing a  $0.6\text{-V}$  threshold. External dividers set the current trip point. The comparator includes a latching capability, that can be made transparent by grounding (or leaving open) the RESET pin. The INA200, INA201, and INA202 devices operate from a single  $2.7$  to  $18\text{-V}$  supply, drawing a maximum of  $1800\text{ }\mu\text{A}$  of supply current. Package options include the very small MSOP-8 and the SO-8. All versions are specified over the extended operating temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .

### 7.2 Functional Block Diagram

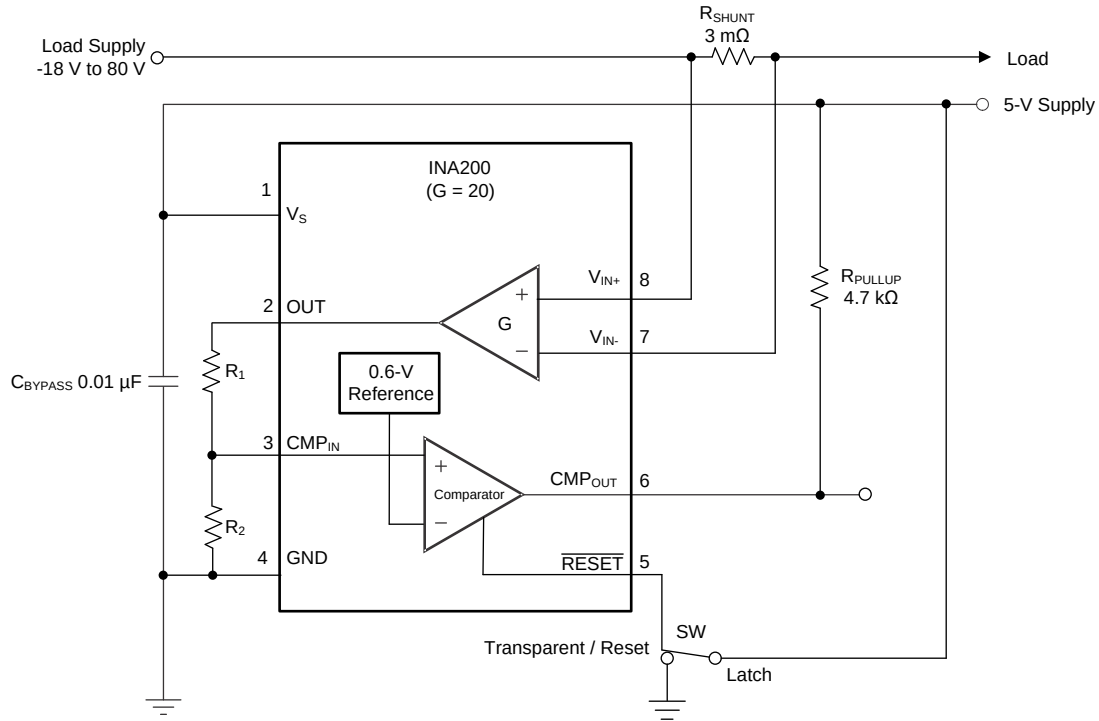


### 7.3 Feature Description

#### 7.3.1 Basic Connections

Figure 26 shows the basic connections of the INA20x devices. The input pins ( $V_{IN+}$  and  $V_{IN-}$ ) must be connected as closely as possible with Kelvin connections to the shunt resistor to minimize any resistance in series with the shunt resistance.

Power-supply bypass capacitors are required for stability. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.



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**图 26. INA200 Basic Connections**

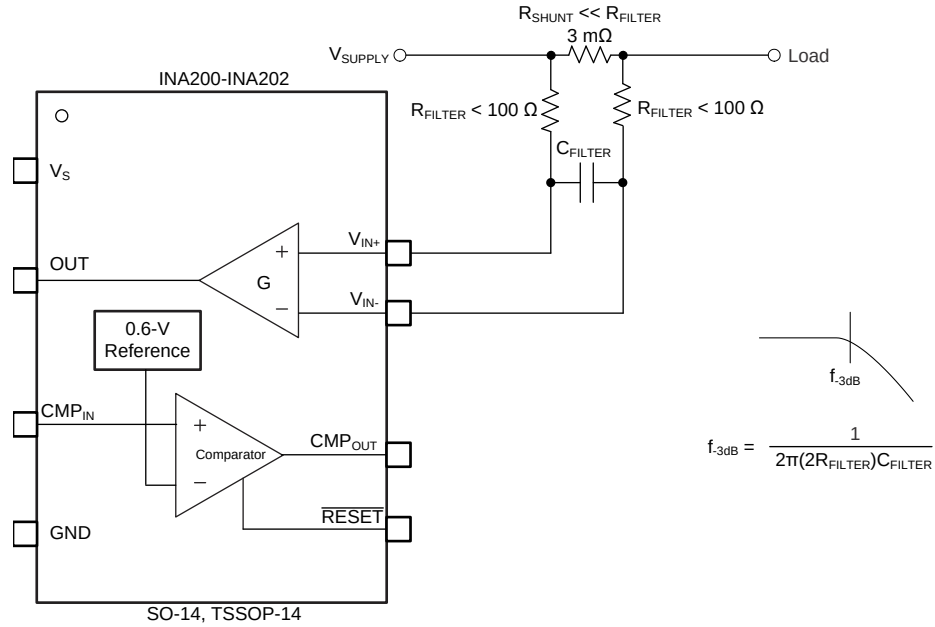
### 7.3.2 Selecting $R_S$

The selected value for the shunt resistor,  $R_S$ , depends on the application and is a compromise between small-signal accuracy and maximum permissible voltage loss in the measurement line. High values of  $R_S$  provide better accuracy at lower currents by minimizing the effects of offset, while low values of  $R_S$  minimize voltage loss in the supply line. For most applications, using an  $R_S$  value that provides a full-scale shunt voltage range of 50 mV to 100 mV results in the best performance. Maximum input voltage for accurate measurements is 500 mV, but output voltage is limited by supply.

### 7.3.3 Comparator

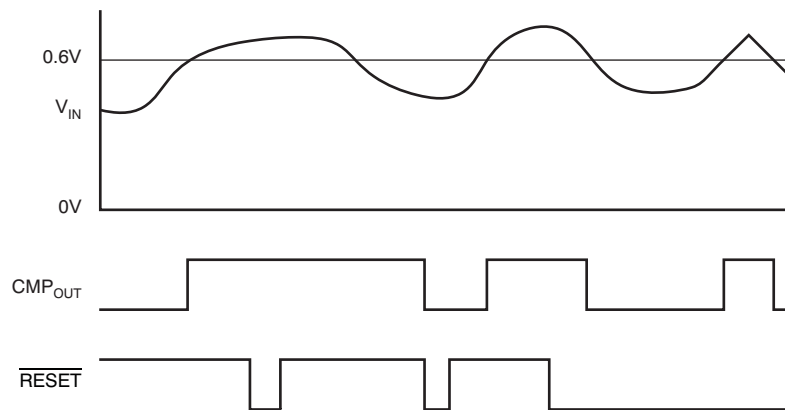
The INA200, INA201, and INA202 devices incorporate an open-drain comparator. This comparator typically has 2 mV of offset and a 1.3-μs (typical) response time. The output of the comparator latches and is reset through the  $\overline{\text{RESET}}$  pin; see 图 28.

When  $V_S$  and  $\overline{\text{RESET}}$  are different, TI recommends adding a low-pass filter (LPF) on the  $\overline{\text{RESET}}$  pin to avoid comparator behavior inconsistent with the data sheet. For instance, with a 12-V supply and a 3.3-V  $\overline{\text{RESET}}$ , a rise time of 400 ns is appropriate. Similarly, with an 18-V supply and a 2.7-V  $\overline{\text{RESET}}$ , a 1-μs rise time is appropriate; see 图 31.

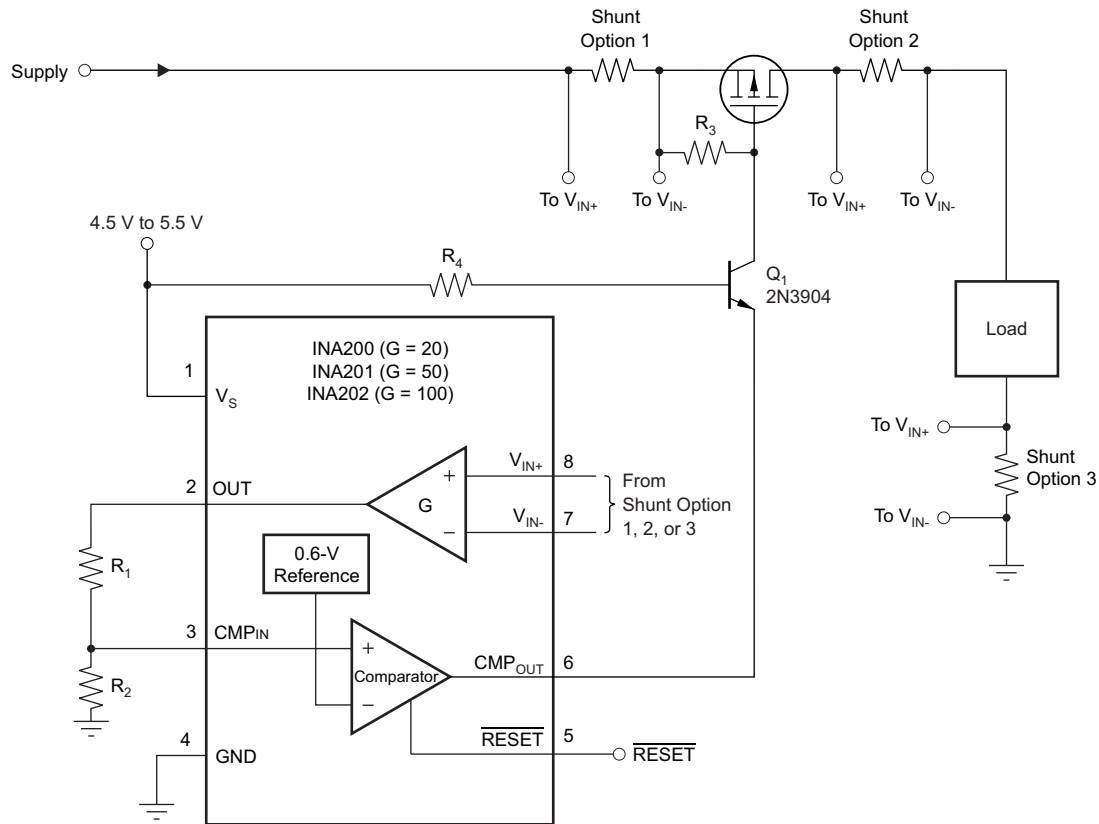


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**图 27. Input Filter (Gain Error: 1.5% to 2.8%)**



**图 28. Comparator Latching Capability**

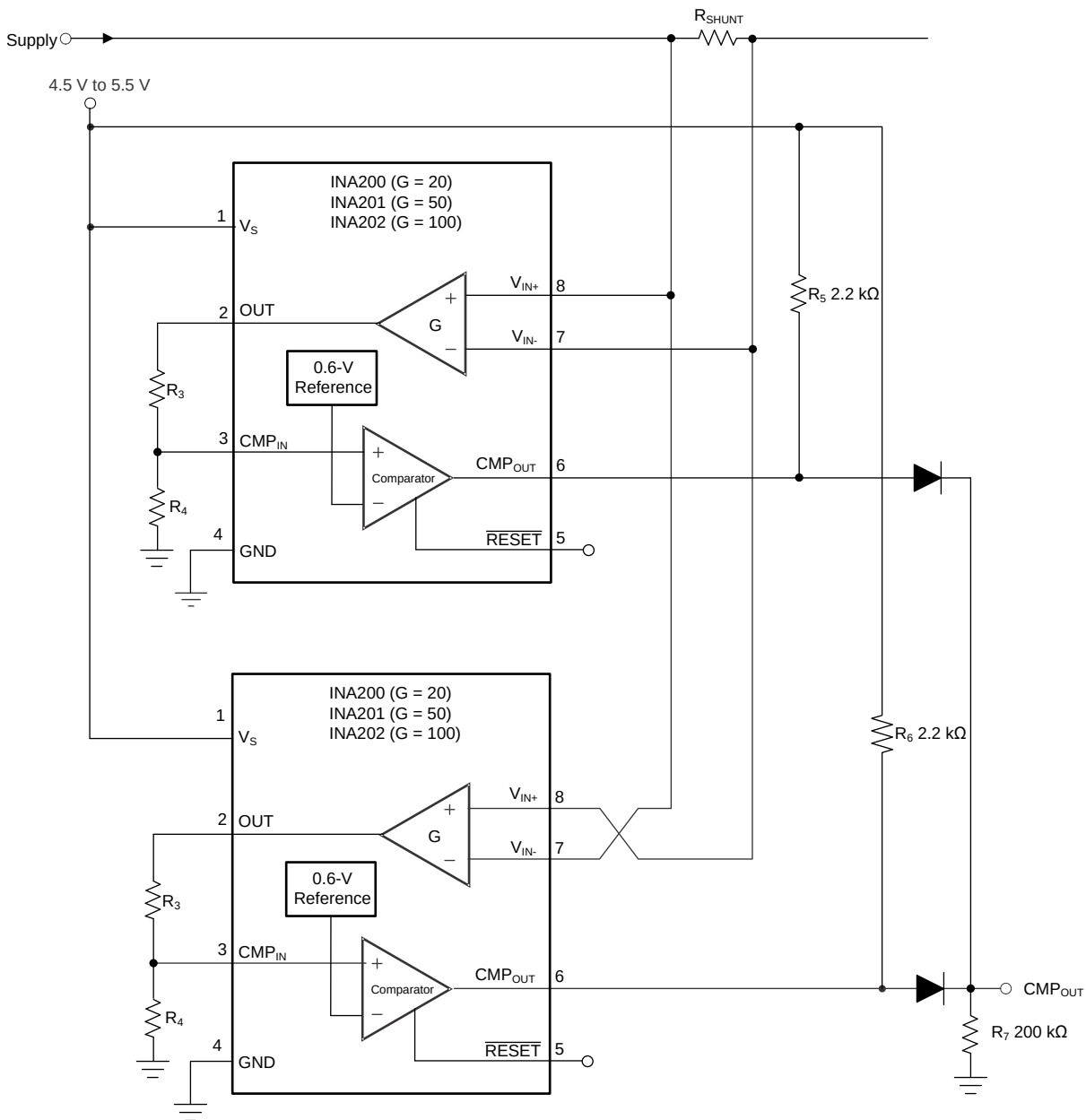


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- (1) Q1 cascodes the comparator output to drive a high-side FET (the 2N3904 shown is good up to 60 V. The shunt can be located in any one of the three locations shown. The latching capability must be used in shutdown applications to prevent oscillation at the trip point.

**图 29. High-Side Switch Overcurrent Shutdown**





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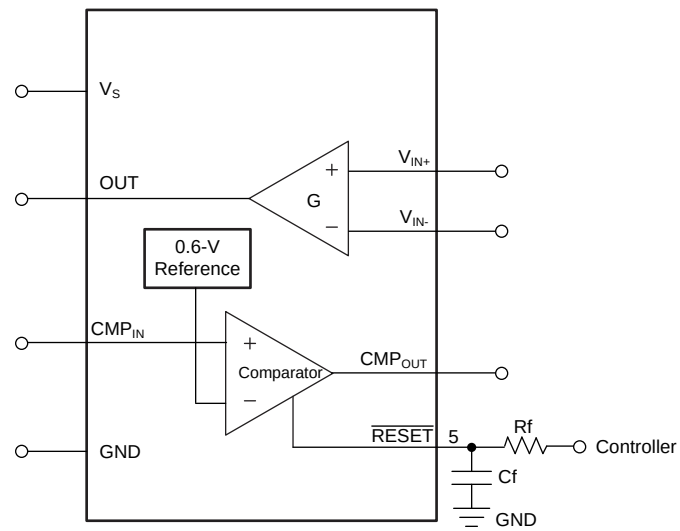
- (1) It is possible to set different limits for each direction.

**图 30. Bidirectional Overcurrent Comparator**

**INA200, INA201, INA202**

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**图 31. Filter on  $\overline{RESET}$  Pin**

## 7.4 Device Functional Modes

### 7.4.1 Input Filtering

An obvious and straightforward location for filtering is at the output of the INA20x series; however, this location negates the advantage of the low output impedance of the internal buffer. The only other option for filtering is at the input pins of the INA20x devices, which is complicated by the internal 5 kΩ + 30% input impedance. This is shown in [图 27](#). Using the lowest possible resistor values minimizes the initial shift in gain and effects of tolerance. The effect on initial gain is shown in [公式 1](#):

$$\text{Gain Error \%} = 100 - \left[ 100 \times \frac{5\text{k}\Omega}{5\text{k}\Omega + R_{\text{FILT}}} \right] \quad (1)$$

Total effect on gain error can be calculated by replacing the 5-kΩ term with 5 kΩ – 30%, (or 3.5 kΩ) or 5 kΩ + 30% (or 6.5 kΩ). The tolerance extremes of  $R_{\text{FILT}}$  can be inserted into the equation. If a pair of 100-Ω 1% resistors are used on the inputs, the initial gain error equals 1.96%. Worst-case tolerance conditions always occur at the lower excursion of the internal 5-kΩ resistor (3.5 kΩ), and the higher excursion of  $R_{\text{FILT}}$  – 3% in this case.

The specified accuracy of the INA20x devices must then be combined in addition to these tolerances. While this discussion treated accuracy worst-case conditions by combining the extremes of the resistor values, it is appropriate to use geometric mean or root sum square calculations to total the effects of accuracy variations.

### 7.4.2 Accuracy Variations as a Result of $V_{\text{SENSE}}$ and Common-Mode Voltage

The accuracy of the INA200, INA201, and INA202 current shunt monitors is a function of two main variables:  $V_{\text{SENSE}}$  ( $V_{\text{IN+}} - V_{\text{IN-}}$ ), common-mode voltage, ( $V_{\text{CM}}$ ), relative to the supply voltage ( $V_{\text{S}}$ ).  $V_{\text{CM}}$  is expressed as  $(V_{\text{IN+}} + V_{\text{IN-}}) / 2$ ; however, in practice,  $V_{\text{CM}}$  is seen as the voltage at  $V_{\text{IN+}}$  because the voltage drop across  $V_{\text{SENSE}}$  is typically small.

This section addresses the accuracy of these specific operating regions:

- Normal Case 1:  $V_{\text{SENSE}} \geq 20 \text{ mV}$ ,  $V_{\text{CM}} \geq V_{\text{S}}$
- Normal Case 2:  $V_{\text{SENSE}} \geq 20 \text{ mV}$ ,  $V_{\text{CM}} < V_{\text{S}}$
- Low  $V_{\text{SENSE}}$  Case 1:  $V_{\text{SENSE}} < 20 \text{ mV}$ ,  $-16 \text{ V} \leq V_{\text{CM}} < 0$
- Low  $V_{\text{SENSE}}$  Case 2:  $V_{\text{SENSE}} < 20 \text{ mV}$ ,  $0 \text{ V} \leq V_{\text{CM}} \leq V_{\text{S}}$
- Low  $V_{\text{SENSE}}$  Case 3:  $V_{\text{SENSE}} < 20 \text{ mV}$ ,  $V_{\text{S}} < V_{\text{CM}} \leq 80 \text{ V}$

#### 7.4.2.1 Normal Case 1: $V_{\text{SENSE}} \geq 20 \text{ mV}$ , $V_{\text{CM}} \geq V_{\text{S}}$

This region of operation provides the highest accuracy. Here, the input offset voltage is characterized and measured using a two-step method. First, the gain is determined by [公式 2](#).

$$G = \frac{V_{\text{OUT1}} - V_{\text{OUT2}}}{100\text{mV} - 20\text{mV}}$$

where

- $V_{\text{OUT1}}$  = output voltage with  $V_{\text{SENSE}} = 100 \text{ mV}$
  - $V_{\text{OUT2}}$  = output voltage with  $V_{\text{SENSE}} = 20 \text{ mV}$
- (2)

Then the offset voltage is measured at  $V_{\text{SENSE}} = 100 \text{ mV}$ , and referred to the input (RTI) of the current shunt monitor, as shown in [Electrical Characteristics: Current-Shunt Monitor](#).

$$V_{\text{OSRTI}} (\text{Referred-To-Input}) = \left[ \frac{V_{\text{OUT1}}}{G} \right] - 100\text{mV} \quad (3)$$

In the [Typical Characteristics](#), [图 7](#) shows the highest accuracy for the this region of operation. In this plot,  $V_{\text{S}} = 12 \text{ V}$ . For  $V_{\text{CM}} \geq 12 \text{ V}$ , the output error is at the minimum value. This case creates the  $V_{\text{SENSE}} \geq 20\text{-mV}$  output specifications in [Electrical Characteristics: Current-Shunt Monitor](#).

## Device Functional Modes (接下页)

### 7.4.2.2 Normal Case 2: $V_{SENSE} \geq 20 \text{ mV}$ , $V_{CM} < V_S$

This region of operation is less accurate than normal case 1 as a result of the common-mode operating area in which the part functions, as shown in the 图 7 curve (图 7). As noted, for this graph  $V_S = 12 \text{ V}$ ; for  $V_{CM} < 12 \text{ V}$ , the output error increases as  $V_{CM}$  decreases to less than  $12 \text{ V}$ , with a typical maximum error of 0.005% at the most negative  $V_{CM} = -16 \text{ V}$ .

### 7.4.2.3 Low $V_{SENSE}$ Case 1: $V_{SENSE} < 20 \text{ mV}$ , $-16 \text{ V} \leq V_{CM} < 0$ and Low $V_{SENSE}$ Case 3: $V_{SENSE} < 20 \text{ mV}$ , $V_S < V_{CM} \leq 80 \text{ V}$

Although the INA200 family of devices are not designed for accurate operation in these regions, some applications are exposed to these conditions. For example, when monitoring power supplies that are switched on and off while  $V_S$  is still applied to the INA20x devices, it is important to know what the behavior of the devices is in these regions.

As  $V_{SENSE}$  approaches  $0 \text{ mV}$ , in these  $V_{CM}$  regions, the accuracy of the device output degrades. A larger-than-normal offset can appear at the current shunt monitor output with a typical maximum value of  $V_{OUT} = 300 \text{ mV}$  for  $V_{SENSE} = 0 \text{ mV}$ . As  $V_{SENSE}$  approaches  $20 \text{ mV}$ ,  $V_{OUT}$  returns to the expected output value with accuracy as shown in [Electrical Characteristics: Current-Shunt Monitor](#). 图 32 shows this effect using the INA202 (gain = 100).

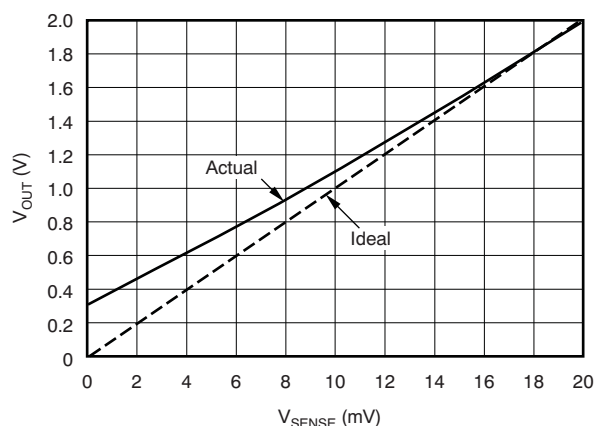
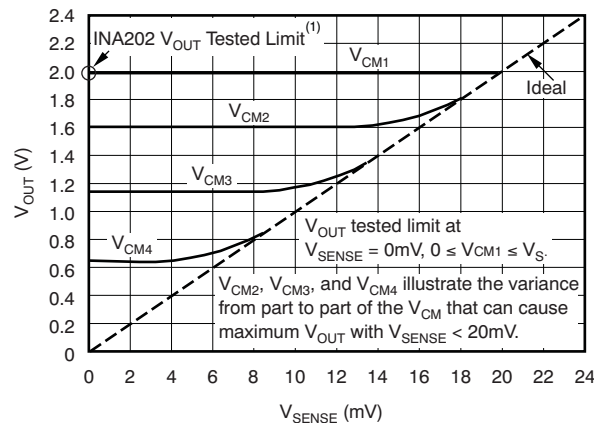


图 32. Example For Low  $V_{SENSE}$  Cases 1 and 3 (INA202, Gain = 100)

### 7.4.2.4 Low $V_{SENSE}$ Case 2: $V_{SENSE} < 20 \text{ mV}$ , $0 \text{ V} \leq V_{CM} \leq V_S$

This region of operation is the least accurate for the INA20x family. To achieve the wide input common-mode voltage range, these devices use two op amp front ends in parallel. One op amp front end operates in the positive input common-mode voltage range, and the other in the negative input region. For this case, neither of these two internal amplifiers dominates and overall loop gain is low. Within this region,  $V_{OUT}$  approaches voltages close to linear operation levels for normal case 2. This deviation from linear operation becomes greatest the closer  $V_{SENSE}$  approaches  $0 \text{ V}$ . Within this region, as  $V_{SENSE}$  approaches  $20 \text{ mV}$ , device operation is closer to that is described in normal case 2. 图 33 shows this behavior for the INA202. The  $V_{OUT}$  maximum peak for this case is tested by maintaining a constant  $V_S$ , setting  $V_{SENSE}$  equal to  $0 \text{ mV}$  and sweeping  $V_{CM}$  from  $0 \text{ V}$  to  $V_S$ . The exact  $V_{CM}$  at which  $V_{OUT}$  peaks during this test varies from device to device, but the  $V_{OUT}$  maximum peak is tested to be less than the specified  $V_{OUT}$  tested limit.

## Device Functional Modes (接下页)



NOTE: (1) INA200  $V_{OUT}$  Tested Limit = 0.4V. INA201  $V_{OUT}$  Tested Limit = 1V.

图 33. Example For Low  $V_{SENSE}$  Case 2 (INA202, Gain = 100)

### 7.4.3 Transient Protection

The -16 to 80 V common-mode range of the INA20x devices is ideal for withstanding automotive fault conditions ranging from 12-V battery reversal up to 80-V transients, since no additional protective components are required up to those levels. In the event that the INA20x devices are exposed to transients on the inputs in excess of their ratings, then external transient absorption with semiconductor transient absorbers (such as Zeners) are required. TI does not recommend using MOVs or VDRs, except when they are used in addition to a semiconductor transient absorber. Select the transient absorber so the absorber does not allow the INA20x devices to be exposed to transients greater than 80 V (that is, allow for transient absorber tolerance and additional voltage due to transient absorber dynamic impedance). Despite the use of internal Zener-type ESD protection, the INA20x devices do not lend themselves to using external resistors in series with the inputs since the internal gain resistors can vary up to  $\pm 30\%$ . (If gain accuracy is not important, then resistors can be added in series with the INA200, INA201, and INA202 inputs with two equal resistors on each input.)

### 7.4.4 Output Voltage Range

The output of the INA20x devices is accurate within the output voltage swing range set by the power supply pin ( $V_S$ .) This performance is best illustrated when using the INA202 (a gain of 100 version), where a 100-mV full-scale input from the shunt resistor requires an output voltage swing of 10 V, and a power-supply voltage sufficient to achieve 10 V on the output.

## 8 Application and Implementation

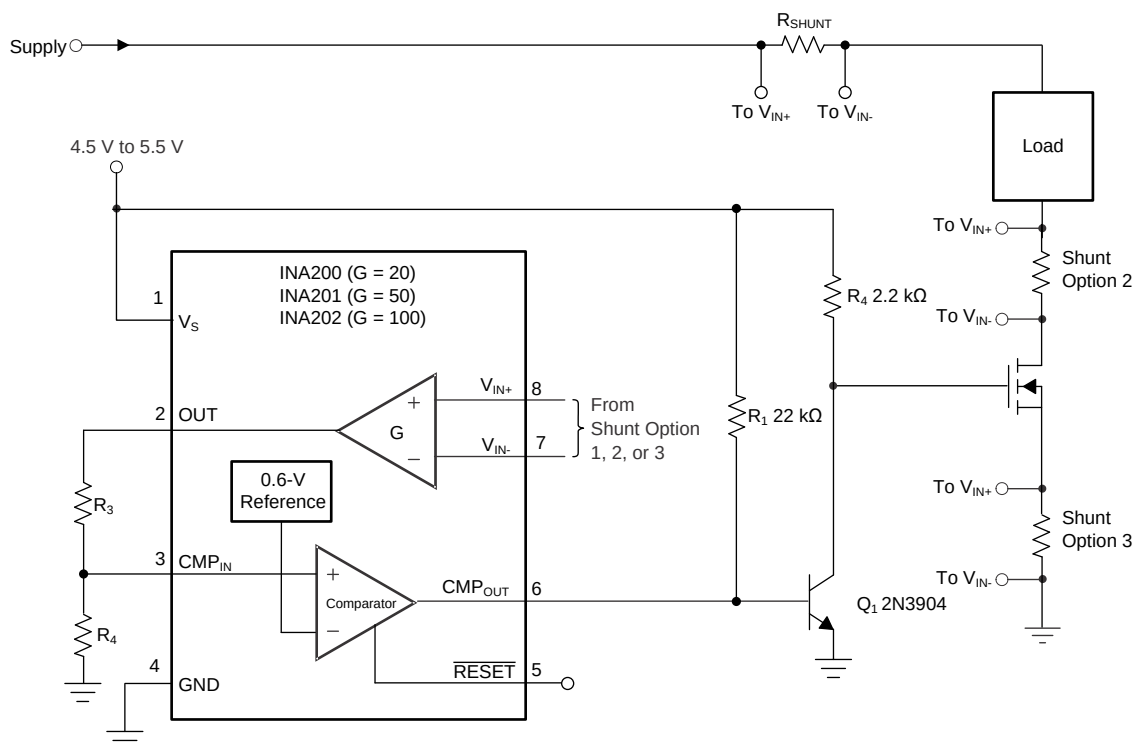
### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The INA20x series is designed to enable simple configuration for detecting overcurrent conditions and current monitoring in an application. This device is individually targeted towards overcurrent detection of a single threshold. However, this device can pair with additional devices and circuitry to create more complex monitoring functional blocks.

### 8.2 Typical Application



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(1) In this case, Q1 inverts the comparator output.

**图 34. Low-Side Switch Overcurrent Shutdown**

#### 8.2.1 Design Requirements

The device measures current through a resistive shunt with current flowing in one direction that enables detection of an overcurrent event only when the differential input voltage exceeds the threshold limit. When the current reaches the set limit of the divider  $R_1 / R_2$ , the output of  $CMP_{OUT}$  transitions high, which turns Q1 on, pulls the gate of the pass-FET low, and turns off the flow off current.

## Typical Application (接下页)

### 8.2.2 Detailed Design Procedure

图 34 显示了设备的基本连接。输入终端 (IN+ 和 IN -) 必须尽可能紧密地连接到电流 sensing 电阻器，以最小化与分流电阻器串联的任何电阻。分流电阻器与输入终端之间的额外电阻会导致测量误差。当输入电流流经此外部输入电阻时，分流电阻器上的电压与到达输入终端的电压不同。

使用 INA20x 的增益和分流值来计算所需的 trip 电流的 OUT 电压。配置 R1 和 R2 使得电流 trip 点等于 0.6-V 参考电压。

### 8.2.3 Application Curve

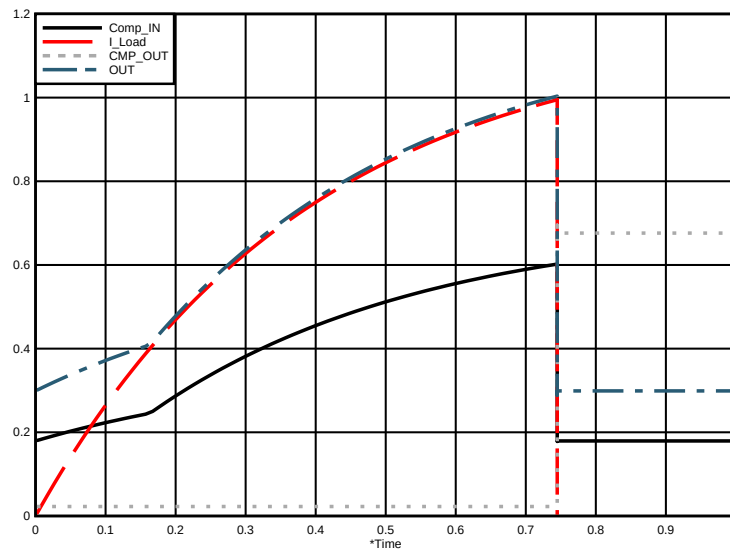


图 35. Low-Side Switch Overcurrent Shutdown Response

## 9 Power Supply Recommendations

The input circuitry of the INA20x devices can accurately measure beyond the power-supply voltage,  $V_s$ . For example, the  $V_s$  power supply is 5 V, whereas the load power-supply voltage is up to 80 V. However, the output voltage range of the OUT pin is limited by the voltages on the power supply pin.

### 9.1 Output vs Supply Ramp Considerations

图 36, 图 37, 和 图 38 显示了典型输出电压的高边和低边配置，具有给定的 ramp 电源电压。这些电源电压上的波动可能需要控制器 incorporate 一个 blanking time 来忽略这些 artifacts。

## Output vs Supply Ramp Considerations (接下页)

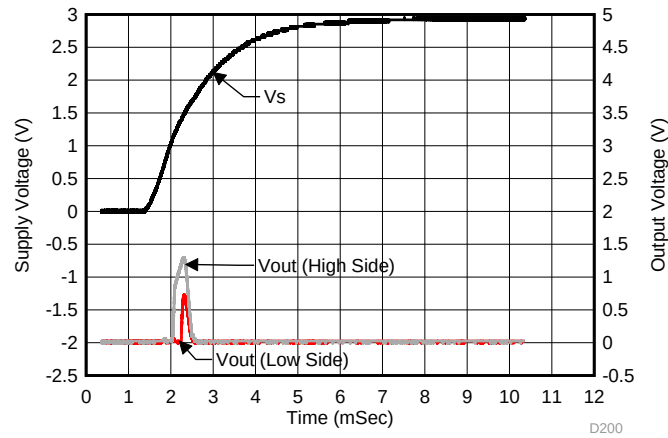


图 36. Analog Output vs Supply Ramp (INA200)

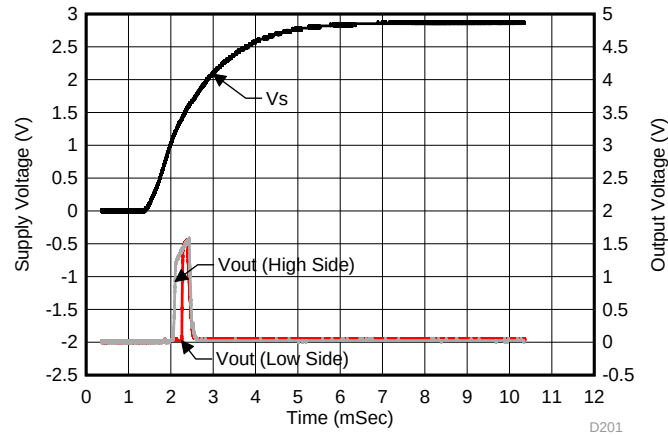


图 37. Analog Output vs Supply Ramp (INA201)

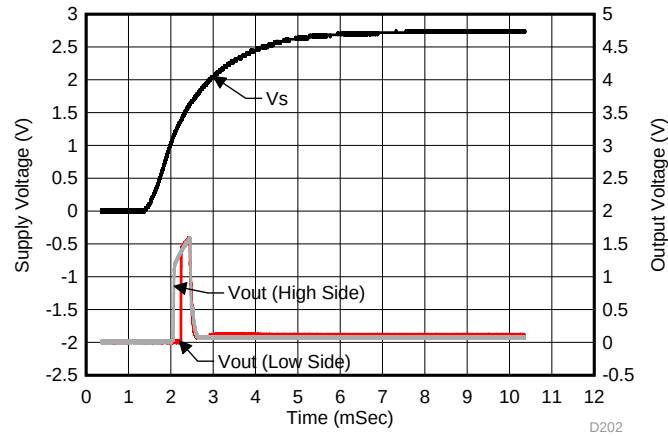


图 38. Analog Output vs Supply Ramp (INA202)



## 10 Layout

### 10.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a Kelvin or 4-wire connection. This connection technique ensures that only the current-sensing resistor impedance is detected between the input pins. Poor routing of the current-sensing resistor commonly results in additional resistance present between the input pins. Given the very-low-ohmic value of the current resistor, any additional high-current carrying impedance causes significant measurement errors.
- The power-supply bypass capacitor must be placed as close as possible to the supply and ground pins. The recommended value of this bypass capacitor is 0.1  $\mu\text{F}$ . Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

### 10.2 Layout Example

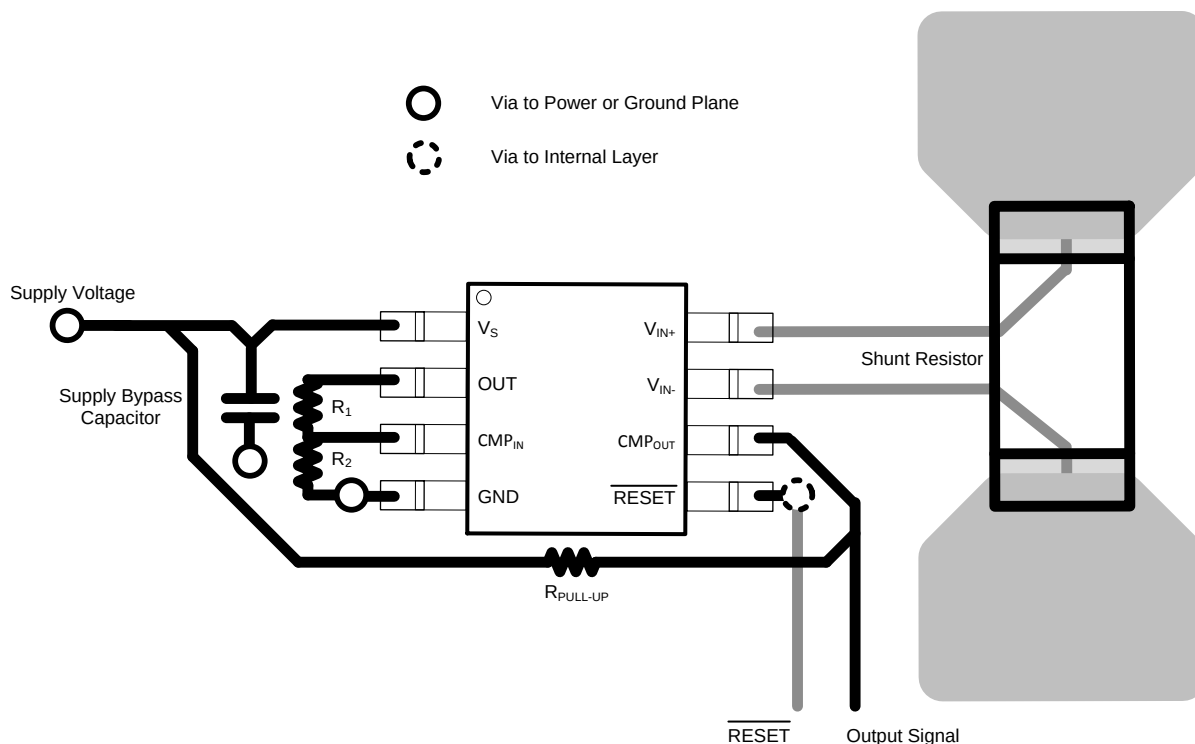


图 39. INA20x Layout Example

## 11 器件和文档支持

### 11.1 相关链接

下面的表格列出了快速访问链接。类别包括技术文档、支持与社区资源、工具和软件，以及申请样片或购买产品的快速链接。

表 1. 相关链接

| 器件     | 产品文件夹                 | 立即订购                  | 技术文档                  | 工具和软件                 | 支持和社区                 |
|--------|-----------------------|-----------------------|-----------------------|-----------------------|-----------------------|
| INA200 | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |
| INA201 | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |
| INA202 | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |

### 11.2 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

**TI E2E™ 在线社区** *TI 的工程师对工程师 (E2E) 社区*。此社区的创建目的在于促进工程师之间的协作。在 [e2e.ti.com](http://e2e.ti.com) 中，您可以咨询问题、分享知识、拓展思路并与同行工程师一道帮助解决问题。

**设计支持** *TI 参考设计支持* 可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。

### 11.3 商标

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

### 11.4 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

### 11.5 Glossary

**SLYZ022** — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。这些数据如有变更，恕不另行通知和修订此文档。如欲获取此数据表的浏览器版本，请参阅左侧的导航。

## PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">INA200AID</a>    | Last Time Buy | Production           | SOIC (D)   8    | 75   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>200A         |
| <a href="#">INA200AIDGKR</a> | Active        | Production           | VSSOP (DGK)   8 | 2500   LARGE T&R      | Yes         | NIPDAU   NIPDAUAG                    | Level-2-260C-1 YEAR               | -40 to 125   | BQH                 |
| INA200AIDGKR.A               | Active        | Production           | VSSOP (DGK)   8 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | BQH                 |
| <a href="#">INA200AIDGKT</a> | Last Time Buy | Production           | VSSOP (DGK)   8 | 250   SMALL T&R       | Yes         | NIPDAU   NIPDAUAG                    | Level-2-260C-1 YEAR               | -40 to 125   | BQH                 |
| <a href="#">INA200AIDR</a>   | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>200A         |
| INA200AIDR.A                 | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>200A         |
| INA200AIDRG4                 | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>200A         |
| INA200AIDRG4.A               | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>200A         |
| <a href="#">INA201AID</a>    | Last Time Buy | Production           | SOIC (D)   8    | 75   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>201A         |
| <a href="#">INA201AIDGKR</a> | Active        | Production           | VSSOP (DGK)   8 | 2500   LARGE T&R      | Yes         | Call TI   Nipdauag<br>  Nipdau       | Level-2-260C-1 YEAR               | -40 to 125   | BQJ                 |
| INA201AIDGKR.A               | Active        | Production           | VSSOP (DGK)   8 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | BQJ                 |
| INA201AIDGKRG4               | Active        | Production           | VSSOP (DGK)   8 | 2500   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   | BQJ                 |
| <a href="#">INA201AIDGKT</a> | Last Time Buy | Production           | VSSOP (DGK)   8 | 250   SMALL T&R       | Yes         | Call TI   Nipdauag<br>  Nipdau       | Level-2-260C-1 YEAR               | -40 to 125   | BQJ                 |
| <a href="#">INA201AIDR</a>   | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>201A         |
| INA201AIDR.A                 | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>201A         |
| INA201AIDRG4                 | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>201A         |
| INA201AIDRG4.A               | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>201A         |
| <a href="#">INA202AID</a>    | Last Time Buy | Production           | SOIC (D)   8    | 75   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>202A         |
| <a href="#">INA202AIDGKR</a> | Active        | Production           | VSSOP (DGK)   8 | 2500   LARGE T&R      | Yes         | NIPDAU   NIPDAUAG                    | Level-2-260C-1 YEAR               | -40 to 125   | BQL                 |

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| INA202AIDGKR.A               | Active        | Production           | VSSOP (DGK)   8 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | BQL                 |
| <a href="#">INA202AIDGKT</a> | Last Time Buy | Production           | VSSOP (DGK)   8 | 250   SMALL T&R       | Yes         | NIPDAU   NIPDAUAG                    | Level-2-260C-1 YEAR               | -40 to 125   | BQL                 |
| <a href="#">INA202AIDR</a>   | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>202A         |
| INA202AIDR.A                 | Active        | Production           | SOIC (D)   8    | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | INA<br>202A         |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF INA200, INA201, INA202 :**

- Automotive : [INA200-Q1](#), [INA201-Q1](#), [INA202-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

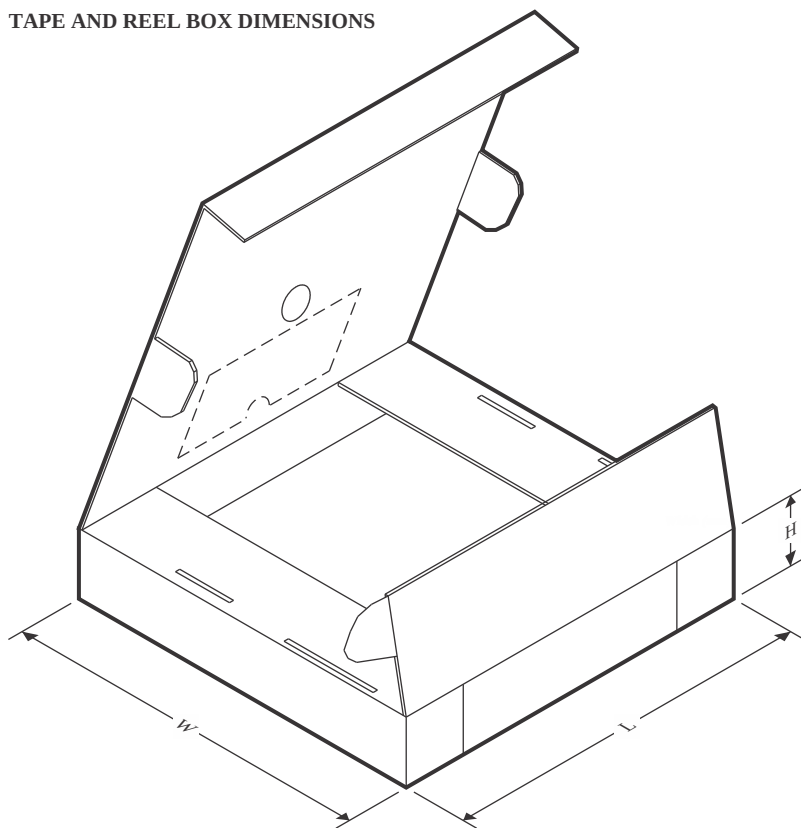
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| INA200AIDGKR | VSSOP        | DGK             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA200AIDGKT | VSSOP        | DGK             | 8    | 250  | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA200AIDR   | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| INA200AIDRG4 | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| INA201AIDGKR | VSSOP        | DGK             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA201AIDGKT | VSSOP        | DGK             | 8    | 250  | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA201AIDGKT | VSSOP        | DGK             | 8    | 250  | 180.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA201AIDGKT | VSSOP        | DGK             | 8    | 250  | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA201AIDR   | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| INA201AIDRG4 | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| INA202AIDGKR | VSSOP        | DGK             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA202AIDGKT | VSSOP        | DGK             | 8    | 250  | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA202AIDGKT | VSSOP        | DGK             | 8    | 250  | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| INA202AIDR   | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |

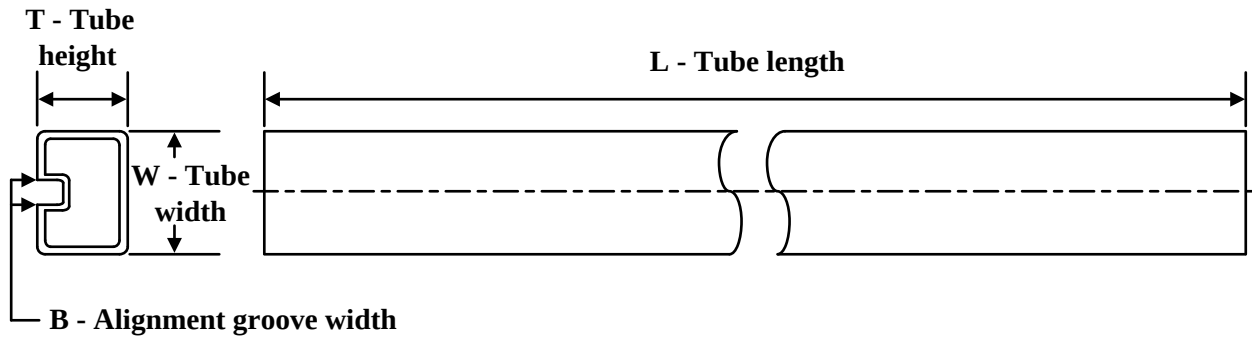
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| INA200AIDGKR | VSSOP        | DGK             | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| INA200AIDGKT | VSSOP        | DGK             | 8    | 250  | 353.0       | 353.0      | 32.0        |
| INA200AIDR   | SOIC         | D               | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| INA200AIDRG4 | SOIC         | D               | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| INA201AIDGKR | VSSOP        | DGK             | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| INA201AIDGKT | VSSOP        | DGK             | 8    | 250  | 366.0       | 364.0      | 50.0        |
| INA201AIDGKT | VSSOP        | DGK             | 8    | 250  | 213.0       | 191.0      | 35.0        |
| INA201AIDGKT | VSSOP        | DGK             | 8    | 250  | 353.0       | 353.0      | 32.0        |
| INA201AIDR   | SOIC         | D               | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| INA201AIDRG4 | SOIC         | D               | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| INA202AIDGKR | VSSOP        | DGK             | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| INA202AIDGKT | VSSOP        | DGK             | 8    | 250  | 353.0       | 353.0      | 32.0        |
| INA202AIDGKT | VSSOP        | DGK             | 8    | 250  | 366.0       | 364.0      | 50.0        |
| INA202AIDR   | SOIC         | D               | 8    | 2500 | 353.0       | 353.0      | 32.0        |

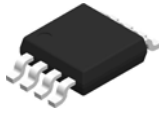
## TUBE



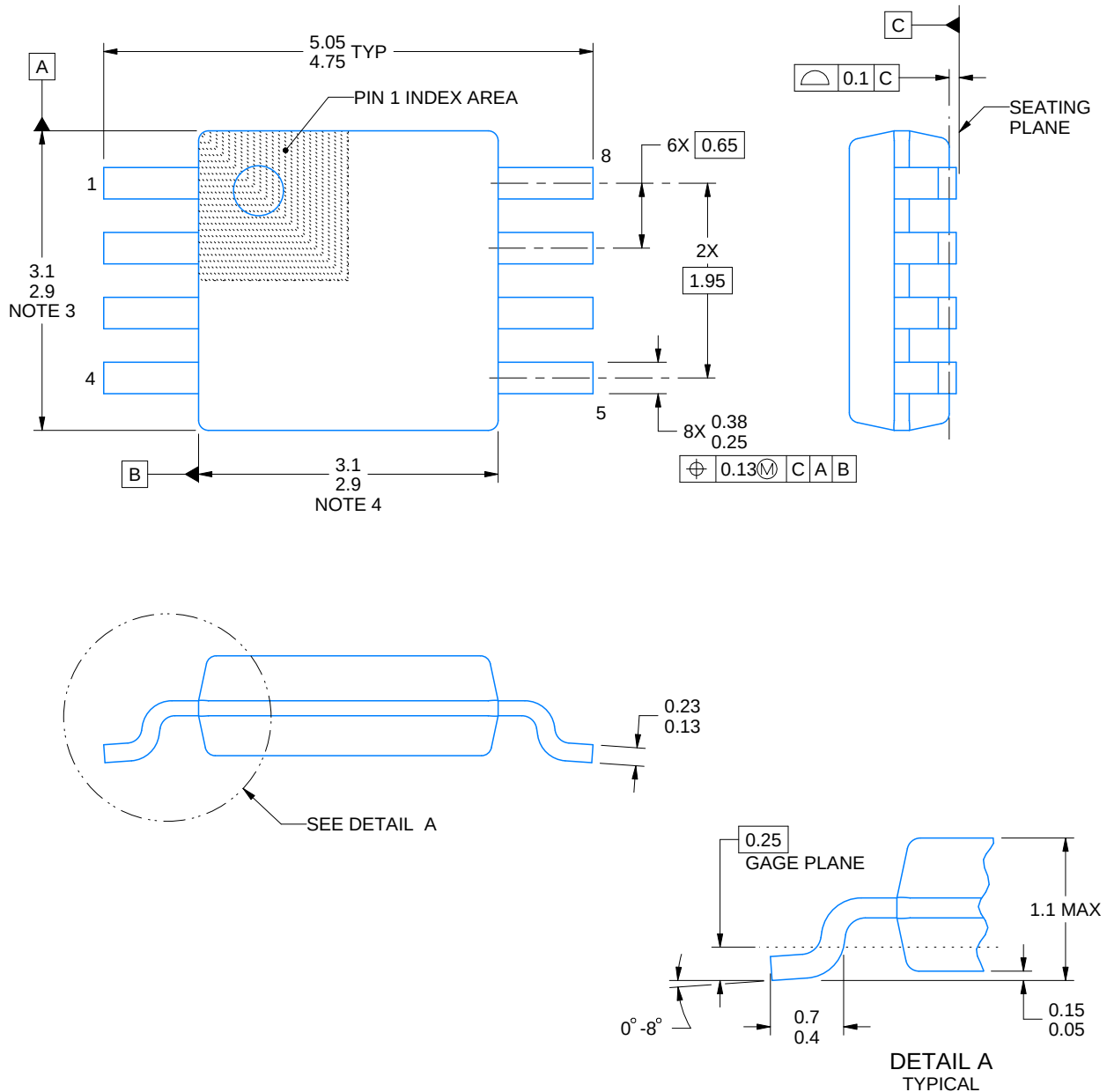
\*All dimensions are nominal

| Device    | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|-----------|--------------|--------------|------|-----|--------|--------|--------|--------|
| INA200AID | D            | SOIC         | 8    | 75  | 506.6  | 8      | 3940   | 4.32   |
| INA201AID | D            | SOIC         | 8    | 75  | 506.6  | 8      | 3940   | 4.32   |
| INA202AID | D            | SOIC         | 8    | 75  | 506.6  | 8      | 3940   | 4.32   |



**DGK0008A****PACKAGE OUTLINE****VSSOP - 1.1 mm max height**

SMALL OUTLINE PACKAGE



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**NOTES:**

PowerPAD is a trademark of Texas Instruments.

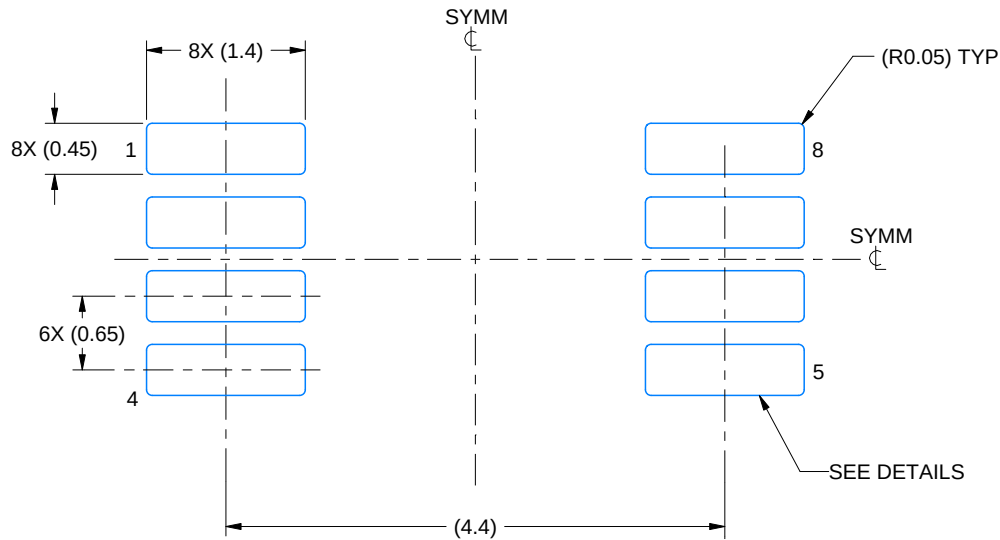
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

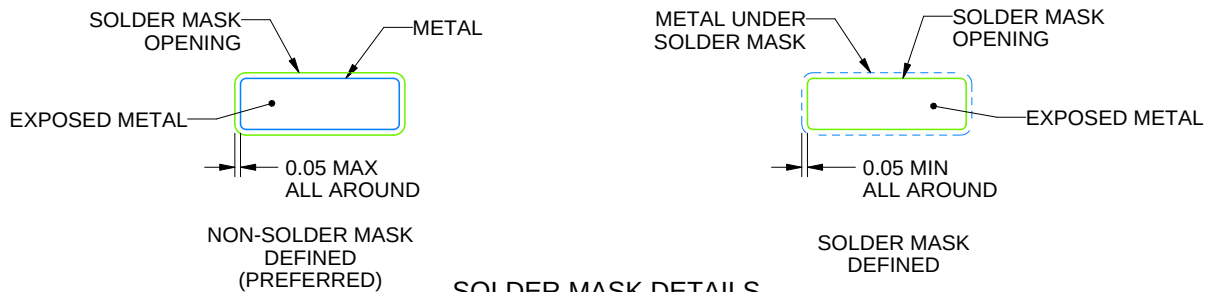
DGK0008A

<sup>TM</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



SOLDER MASK DETAILS

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NOTES: (continued)

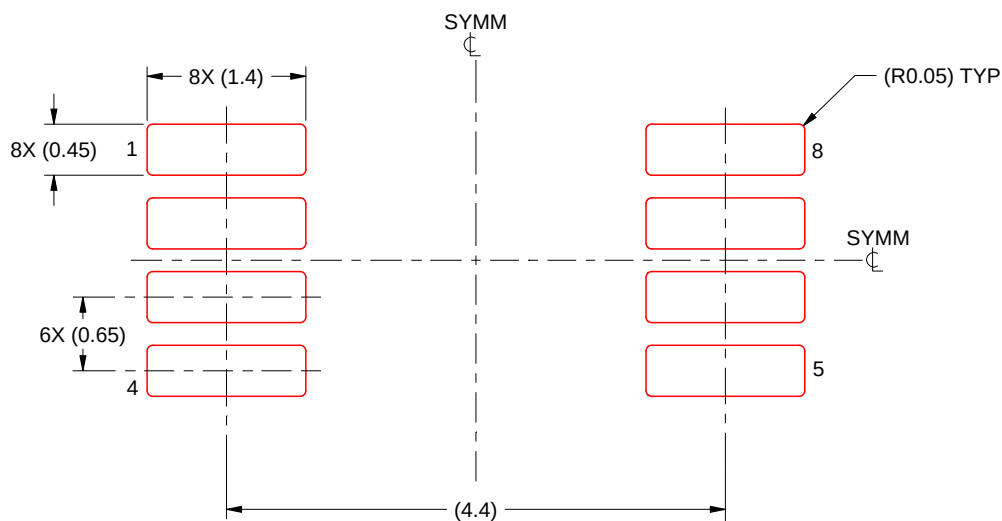
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

## EXAMPLE STENCIL DESIGN

DGK0008A

<sup>TM</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
SCALE: 15X

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NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.



## PACKAGE OUTLINE

**SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



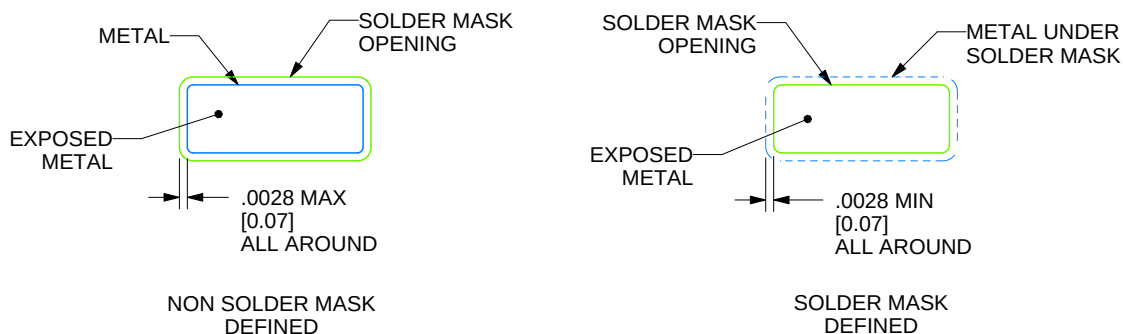
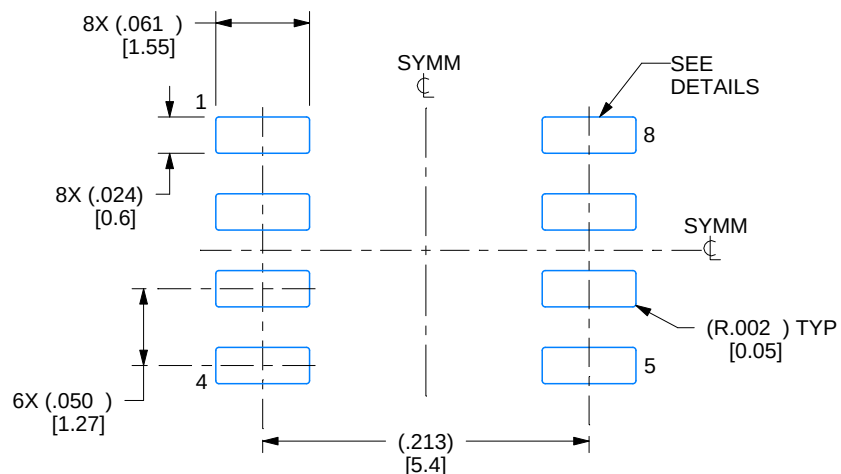
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

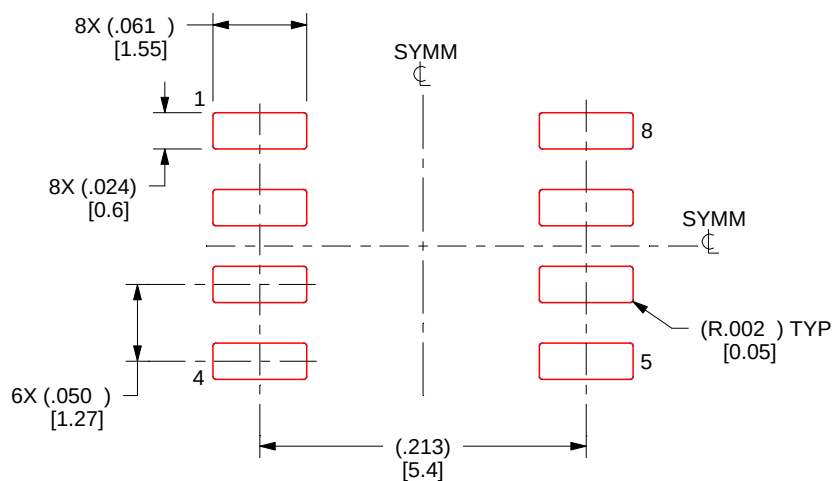
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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